

# SANYO Semiconductors DATA SHEET

SBS813 — Low VF Schottky Barrier Diode 30V, 3.0A Rectifier

## **Applications**

· High frequency rectification (switching regulators, converters, choppers).

#### **Features**

- · Small switching noise.
- Low forward voltage (IF=3A, VF max=0.42V).
- · Ultrasmall package permitting applied sets to be small and slim.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		30	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		30	V
Average Output Current	IO		3.0	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	20	Α
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

#### Electrical Characteristics at Ta=25°C

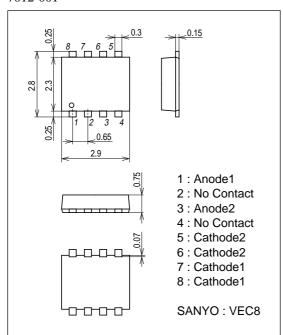
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Reverse Voltage	VR	I <sub>R</sub> =2.0mA	30			٧
Forward Voltage	VF	IF=2.0A		0.335	0.385	V
		IF=3.0A		0.37	0.42	٧
Reverse Current	IR	V <sub>R</sub> =15V			1.4	mA
Interterminal Capacitance	С	V <sub>R</sub> =10V, f=1MHz		90		pF
Reverse Recovery Time	t <sub>rr</sub>	IF=IR=100mA, See specified Test Circuit.			20	ns
Thermal Resistance	Rth(j-a)	Mouted on a ceramic board (1200mm <sup>2</sup> X0.8mm)		50		°C / W

Marking : SF

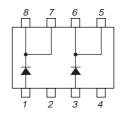
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### **Package Dimensions**

unit : mm 7012-001



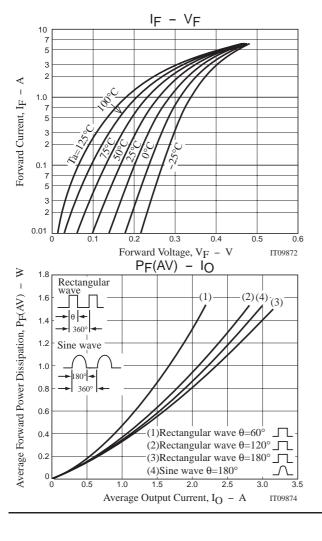
#### **Electrical Connection**

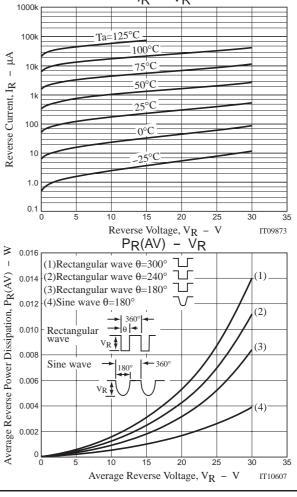


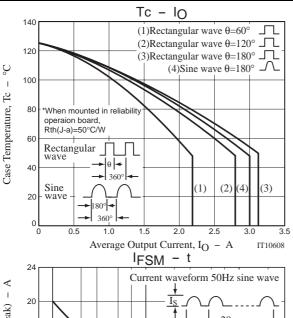
1 : Anode1
2 : No Contact
3 : Anode2
4 : No Contact
5 : Cathode2
6 : Cathode2
7 : Cathode1

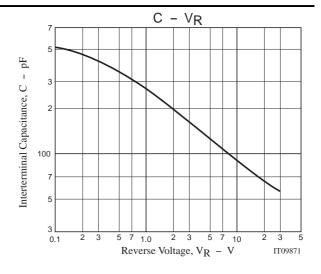
8: Cathode1

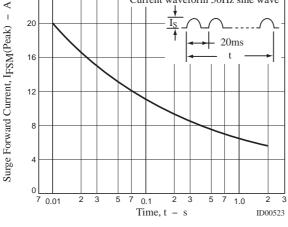
Top view











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